NSN 5961-01-241-5351

Transistor - Page 1 of 1

Fiig: A110a0



View Online at https://aerobasegroup.com/nsn/5961-01-241-5351 **Inclosure Material:** Metal **Overall Length:** 1.573 inches **Overall Height:** 0.350 inches **Overall Width:** 1.050 inches **Mounting Facility Quantity: Internal Configuration:** Junction contact Joint Electronic Device Engineering Council/jedec/case Outline Designation: To-3 **Mounting Method:** Unthreaded hole **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 450.0 breakdown voltage, collector-to-emitter, base open **Current Rating Per Characteristic:** 10.00 amperes zero-gate-voltage source current blank **Power Rating Per Characteristic:** 220.0 watts small-signal input power, common-collector absolute **Transfer Ratio:** 10.0 static forward current transfer ratio, common-emitter and 40.0 static forward current transfer ratio, common-emitter **Maximum Operating Tempurature Per Measurement Point:** 175.0 degrees celsius junction **Special Features:** Junction pattern arrangement: npn **Terminal Type And Quantity:** 2 pin and 1 case **Specification Data:** 07421-345-214-046 manufacturers specification control Shelf Life: N/a **Unit Of Measure: Demilitarization:** No